

# TC4431/TC4432

# 1.5A High-Speed 30V MOSFET Drivers

### **Features**

- Passes AEC-Q100 Automotive Reliability Testing
- · High-Peak Output Current: 1.5A
- · Wide Input Supply Operating Range:
  - 4.5V to 30V
- · High Capacitive Load Drive Capability:
  - 1000 pF in 25 ns
- Short Delay Time: <78 ns (Typical)
- · Low Supply Current:
  - With Logic '1' Input: 2.5 mA
  - With Logic '0' Input: 300 μA
- Low Output Impedance: 7Ω
- Latch-Up Protected: Will Withstand >300 mA Reverse Current
- Electrostatic Discharge (ESD) Protected: 4 kV

### **Applications**

- · Small Motor Drive
- · Power MOSFET Driver
- · Driving Bipolar Transistors

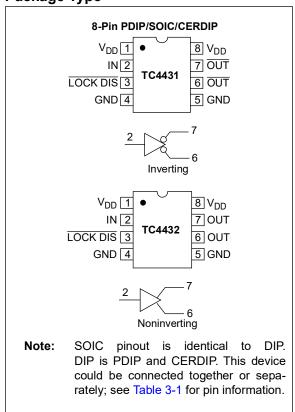
# **General Description**

The TC4431/TC4432 are 30V CMOS buffers/drivers suitable for use in high-side driver applications. They do not latch up under any conditions within their power and voltage ratings. They can accept, without damage or logic upset, up to 300 mA of reverse current (of either polarity) being forced back into their outputs. All terminals are fully protected against electrostatic discharge up to 4 kV.

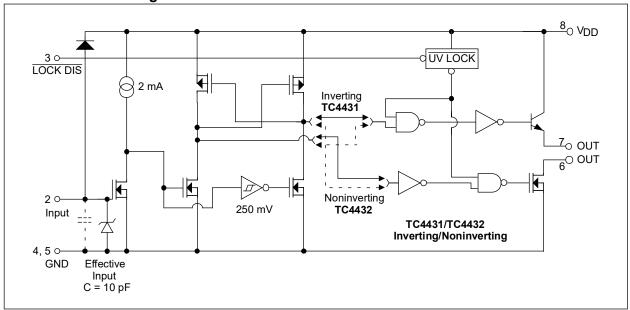
Undervoltage Lockout (UVLO) circuitry forces the output to a low state when the input supply voltage drops below 7V. For operation at lower voltages, disable the lockout and start-up circuit by grounding pin 3 (LOCK DIS); for all other situations, pin 3 (LOCK DIS) should be left floating. The undervoltage lockout and start-up circuit gives brown out protection when driving MOSFETs.

The TC4431 and TC4432 are AEC-Q100 qualified for automotive applications.

# **Package Type**



# **Functional Block Diagram**



### 1.0 ELECTRICAL CHARACTERISTICS

# **Absolute Maximum Ratings†**

Supply Voltage	36V
Input Voltage (Note 1)	
Package Power Dissipation (T <sub>A</sub> ≤ 70°C)	
PDIP	730 mW
CERDIP	800 mW
SOIC	
Maximum Junction Temperature (T <sub>J</sub> )	+150°C
Storage Temperature Range	65°C to +150°C

**† Notice:** Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specification is not intended. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

### DC CHARACTERISTICS

<b>Electrical Specifications:</b> Unless otherwise noted, $T_A = +25^{\circ}C$ with $4.5V \le V_{DD} \le 30V$ .							
Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions	
Input							
Logic '1', High Input Voltage	$V_{IH}$	2.4	_	_	V		
Logic '0', Low Input Voltage	$V_{IL}$	_	_	0.8	V		
Input Current (Note 1)	I <sub>IN</sub>	-1	_	1	μA	$0V \le V_{IN} \le 12V$	
Output							
High Output Voltage	V <sub>OH</sub>	V <sub>DD</sub> -1.0	V <sub>DD</sub> -0.8		V	I <sub>OUT</sub> = 100 mA	
Low Output Voltage	$V_{OL}$	_	_	0.025	V		
Output Resistance	Ro	_	7	10	Ω	I <sub>OUT</sub> = 10 mA, V <sub>DD</sub> = 30V	
Peak Output Current	I <sub>PK</sub>	_	3.0	_	Α	Source: V <sub>DD</sub> = 30V	
		_	1.5	_		Sink: V <sub>DD</sub> = 30V	
Latch-Up Protection Withstand Reverse Current	I <sub>REV</sub>	_	0.3	_	А	Duty cycle $\leq$ 2%, t $\leq$ 300 $\mu$ s	
Switching Time (Note 2)					•		
Rise Time	t <sub>R</sub>	_	25	40	ns	Figure 4-1	
Fall Time	t <sub>F</sub>	_	33	50	ns	Figure 4-1	
Delay Time	t <sub>D1</sub>	_	62	80	ns	Figure 4-1	
Delay Time	t <sub>D2</sub>	_	78	90	ns	Figure 4-1	
Power Supply				•	,		
Power Supply Current	I <sub>S</sub>	_	2.5	4	mA	V <sub>IN</sub> = 3V	
		_	0.3	0.4		V <sub>IN</sub> = 0V	
Start-Up Threshold	V <sub>S</sub>	_	8.4	10	V		
Drop-Out Threshold	$V_{DO}$	7	7.7	_	V	Note 3	

- Note 1: For inputs >12V, add a 1 k $\Omega$  resistor in series with the input. See Section 2.0 "Typical Performance Curves" for input current graph.
  - 2: Switching times are ensured by design.
  - **3:** For operation below 7V, pin 3 (LOCK DIS) should be tied to ground to disable the lockout and start-up circuit; otherwise, pin 3 must be left floating.

# DC CHARACTERISTICS (OVER OPERATING TEMPERATURE RANGE)

Electrical Specifications: Un	less other	wise noted, ov	er operatin	g temper	ature ra	ange with $4.5V \le V_{DD} \le 30V$ .
Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions
Input				•	•	
Logic '1', High Input Voltage	V <sub>IH</sub>	2.4	_	_	V	
Logic '0', Low Input Voltage	V <sub>IL</sub>	_	_	0.8	V	
Input Current (Note 1)	I <sub>IN</sub>	-10	_	10	μA	$0V \le V_{IN} \le 12V$
Output			•	•	•	•
High Output Voltage	V <sub>OH</sub>	V <sub>DD</sub> -1.2	_	_	V	I <sub>OUT</sub> = 100 mA
Low Output Voltage	V <sub>OL</sub>	_	_	0.025	V	
Output Resistance	R <sub>O</sub>	_	_	12	Ω	I <sub>OUT</sub> = 10 mA, V <sub>DD</sub> = 30V
Switching Time (Note 2)						
Rise Time	t <sub>R</sub>	_	_	60	ns	Figure 4-1
Fall Time	t <sub>F</sub>	_	_	70	ns	Figure 4-1
Delay Time	t <sub>D1</sub>	_	_	100	ns	Figure 4-1
Delay Time	t <sub>D2</sub>	_	_	110	ns	Figure 4-1
Power Supply			•	•	•	•
Power Supply Current	I <sub>S</sub>	_	_	6	mA	V <sub>IN</sub> = 3V
		_	_	0.7		V <sub>IN</sub> = 0V
Start-Up Threshold	V <sub>S</sub>	_	8.4	10	V	
Drop-Out Threshold	$V_{DO}$	7	7.7	_	V	Note 3

Note 1: For inputs >12V, add a 1 k $\Omega$  resistor in series with the input. See Section 2.0 "Typical Performance Curves" for input current graph.

- 2: Switching times are ensured by design.
- **3:** For operation below 7V, pin 3 (LOCK DIS) should be tied to ground to disable the lockout and start-up circuit; otherwise, pin 3 must be left floating.

# **TEMPERATURE CHARACTERISTICS**

<b>Electrical Specifications:</b> Unless otherwise noted, all parameters apply with $4.5V \le V_{DD} \le 30V$ .							
Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions	
Temperature Ranges							
Specified Temperature Range (C)	T <sub>A</sub>	0	_	+70	°C		
Specified Temperature Range (E)	T <sub>A</sub>	-40	_	+85	°C		
Specified Temperature Range (V)	T <sub>A</sub>	-40	_	+125	°C		
Maximum Junction Temperature	TJ	_	_	+150	°C		
Storage Temperature Range	T <sub>A</sub>	-65	_	+150	°C		
Package Thermal Resistances:							
Thermal Resistance, 8L-SOIC	$\theta_{JA}$	_	155	_	°C/W		
Thermal Resistance, 8L-PDIP	$\theta_{JA}$	_	125	_	°C/W		
Thermal Resistance, 8L-CERDIP	$\theta_{JA}$	_	150		°C/W		

# 2.0 TYPICAL PERFORMANCE CURVES

**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

**Note:** Unless otherwise indicated,  $T_A$  = +25°C with 4.5V  $\leq$  V<sub>DD</sub>  $\leq$  30V.

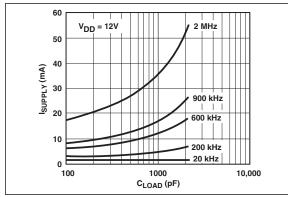


FIGURE 2-1: Supply Current vs. Capacitive Load.

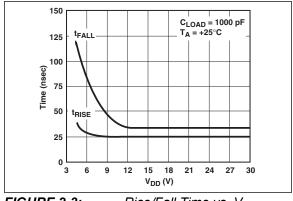
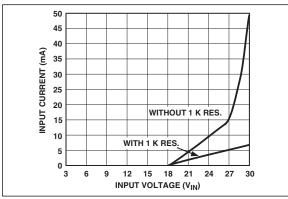
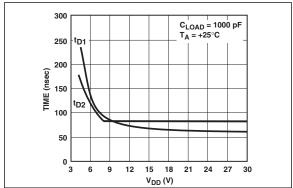


FIGURE 2-3: Rise/Fall Time vs.  $V_{DD}$ .



**FIGURE 2-2:** Input Current vs. Input Voltage.



**FIGURE 2-4:**  $t_{D1}$  and  $t_{D2}$  Delay vs.  $V_{DD}$ .

### 3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: Pin Function Table

Pin No.	Symbol	Description
1	V <sub>DD</sub>	Supply Input, 4.5V to 30V
2	IN	TTL/CMOS Compatible Input
3	LOCK DIS	Input Pin, Enable/Disable for UVLO
4	GND	Ground
5	GND	Ground
6	OUT	Drive Output, Pull Down
7	OUT	Drive Output, Pull Up
8	V <sub>DD</sub>	Supply Input, 4.5V to 30V

# 3.1 Supply Input (V<sub>DD</sub>)

The  $V_{DD}$  input is the bias supply input for the MOSFET driver and is rated for 4.5V to 30V with respect to the ground pins. The  $V_{DD}$  input should be bypassed to ground with a local ceramic capacitor. The value of this capacitor should be chosen based on the capacitive load that is being driven.

### 3.2 Control Input (IN)

The MOSFET driver input is a TTL/CMOS compatible input with 250 mV of hysteresis between the high and low threshold voltages. If an input signal level of greater than 12V is applied to the device, a series current limiting resistor is recommended.

# 3.3 Lockout Disable (LOCK DIS)

The lockout pin enables/disables the undervoltage lockout feature of the device. If undervoltage lockout is desired (output is not enabled until the bias voltage reaches 8.4V (typical) on the rising edge and is disabled when the bias voltage reaches 7.7V (typical) on the falling edge), the lockout pin should be left floating. If operation below 7V is desired, the lockout pin should be tied to ground.

# 3.4 Ground (GND)

The ground pins are the return path for the bias current and for the high-peak currents which discharge the load capacitor. Both ground pins should be used to ensure proper operation. The ground pins should be tied into a ground plane or have short traces to the bias supply source return.

### 3.5 Drive Output (OUT)

The TC4431/TC4432 devices have individual source and sink output pins. This feature can be used to adjust the rise and fall time independently by adding separate charge and discharge resistors external to the device. Pin 7 (source output) can source 3A peak currents into capacitive loads and pin 6 (sink output) can sink 1.5A peak currents from a capacitive load.

# 4.0 APPLICATION INFORMATION

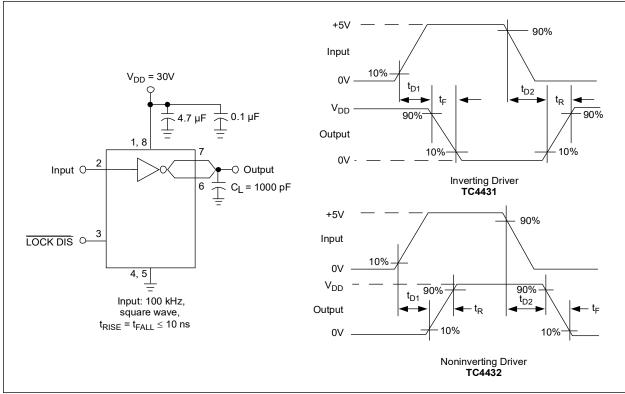
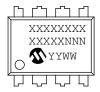


FIGURE 4-1: Switching Time Test Circuit.

### 5.0 PACKAGING INFORMATION

# 5.1 Package Marking Information

8-Lead CERDIP (300 mil)



8-Lead PDIP (300 mil)



8-Lead SOIC (150 mil)



### Example:



### Example:



### Example:



**Legend:** XX...X Customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

(e3) Pb-free JEDEC designator for Matte Tin (Sn)

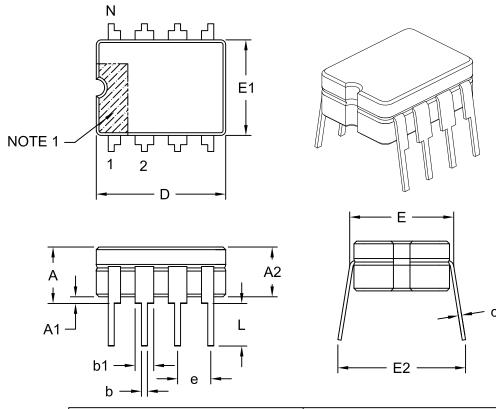
This package is Pb-free. The Pb-free JEDEC designator (e3)

can be found on the outer packaging for this package.

In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

# 8-Lead Ceramic Dual In-Line (JA) ~ .300" Body [CERDIP]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Units		INCHES		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	е		.100 BSC	
Top to Seating Plane	Α	Ē	-	.200
Base to Seating Plane §	A1	.015	-	•
Ceramic Package Height	A2	.140	-	.175
Shoulder to Shoulder Width	E	.290	-	.320
Ceramic Pkg. Width	E1	.230	.248	.300
Overall Length	D	.370	.380	.400
Tip to Seating Plane	L	.125	-	.200
Lead Thickness	С	.008	-	.015
Upper Lead Width	b1	.045	-	.065
Lower Lead Width	b	.015	-	.023
Overall Row Spacing	E2	.314	-	.410

### Notes:

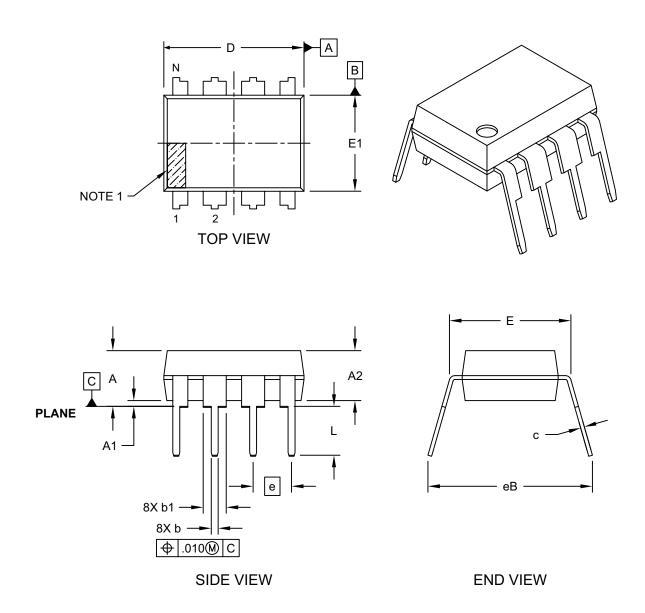
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-001C

# 8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

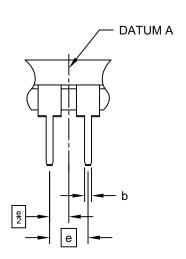
**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging

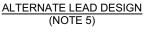


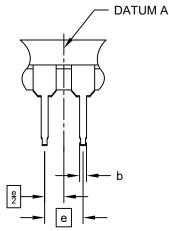
Microchip Technology Drawing No. C04-018-P Rev F Sheet 1 of 2

# 8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging







	INCHES				
Dimension Limits		MIN	NOM	MAX	
Number of Pins	N		8		
Pitch	е		.100 BSC		
Top to Seating Plane	Α	-	-	.210	
Molded Package Thickness	A2	.115	.130	.195	
Base to Seating Plane	A1	.015	-	-	
Shoulder to Shoulder Width	Е	.290	.310	.325	
Molded Package Width	E1	.240	.250	.280	
Overall Length	D	.348	.365	.400	
Tip to Seating Plane	L	.115	.130	.150	
Lead Thickness	С	.008	.010	.015	
Upper Lead Width	b1	.040	.060	.070	
Lower Lead Width	b	.014	.018	.022	
Overall Row Spacing §	eВ	-	-	.430	

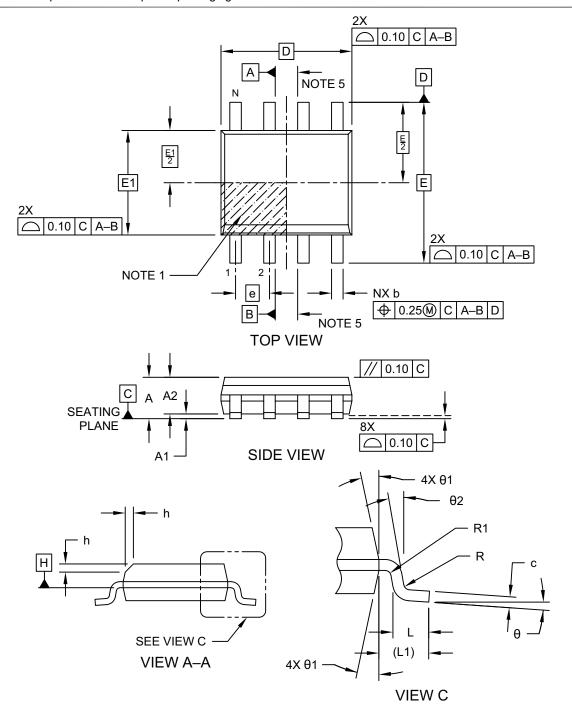
### Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M
  - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 5. Lead design above seating plane may vary, based on assembly vendor.

Microchip Technology Drawing No. C04-018-P Rev F Sheet 2 of 2

# 8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 ln.) Body [SOIC]

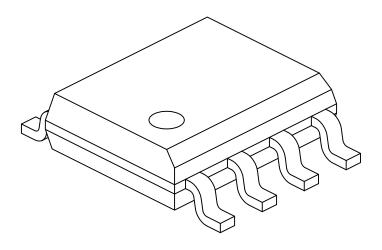
**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing No. C04-057-SN Rev K Sheet 1 of 2

# 8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 ln.) Body [SOIC]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimension	Limits	MIN	NOM	MAX	
Number of Pins	Ν	8			
Pitch	е		1.27 BSC		
Overall Height	Α	1	_	1.75	
Molded Package Thickness	A2	1.25	-	-	
Standoff §	A1	0.10	-	0.25	
Overall Width	Е	6.00 BSC			
Molded Package Width	E1	3.90 BSC			
Overall Length	D	4.90 BSC			
Chamfer (Optional)	h	0.25 – 0.50			
Foot Length	L	0.40	-	1.27	
Footprint	L1		1.04 REF		
Lead Thickness	С	0.17	_	0.25	
Lead Width	b	0.31	-	0.51	
Lead Bend Radius	R	0.07	_	_	
Lead Bend Radius	R1	0.07	_	_	
Foot Angle	θ	0° – 8°			
Mold Draft Angle	θ1	5°	_	15°	
Lead Angle	θ2	0°	_	_	

#### Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

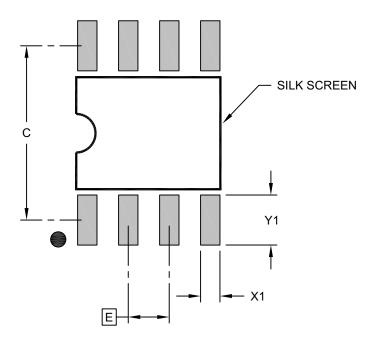
REF: Reference Dimension, usually without tolerance, for information purposes only.

5. Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-057-SN Rev K Sheet 2 of 2

# 8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 ln.) Body [SOIC]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



# RECOMMENDED LAND PATTERN

	N	IILLIMETER	S	
Dimension Limits		MIN	NOM	MAX
Contact Pitch	Е	1.27 BSC		
Contact Pad Spacing	С		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

### Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-2057-SN Rev K

### APPENDIX A: REVISION HISTORY

# Revision E (December 2022)

The following is the list of modifications:

- Added AEC-Q100 Automotive Qualification to Features, General Description and examples in Product Identification System.
- Updated Section 5.0 "Packaging Information".
- Made minor formating changes throughout the document.

# **Revision D (December 2007)**

The following is the list of modifications:

- Section 1.0 "Electrical Characteristics": Added V temperature information to Temperature Characteristics table.
- · Added Revision History.
- Added V temperature range to Product identification System page.

# Revision C (May 2003)

· Undocumented changes.

# Revision B (May 2002)

· Undocumented changes.

# Revision A (April 2002)

· Original Release of this Document.

TC443	31	/T	$C\Delta$	43	2
$I \cup TT$	JI.	/ I '	VT	T	

NOTES:

# PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	<u> </u>	Examples:
 Device		a) TC4431COA: 1.5A MOSFET driver, SOIC package, 0°C to +70°C.
	Range	b) TC4431EJA: 1.5A MOSFET driver, CERDIP package, -40°C to +85°C.
Device:	TC4431: 1.5A High-Speed 30V MOSFET Driver,	c) TC4431VPA: 1.5A MOSFET driver, PDIP package, -40°C to +125°C.
	TC4432: 1.5A High-Speed 30V MOSFET Driver,	
	Noninverting	a) TC4432CPA: 1.5A MOSFET driver, PDIP package, 0°C to +70°C.
Temperature	C = 0°C to +70°C	b) TC4432EPA: 1.5A MOSFET driver, PDIP package, -40°C to +85°C.
Range:	E = $-40^{\circ}$ C to +85°C V = $-40^{\circ}$ C to +125°C	c) TC4432VOA713: Tape and Reel, 1.5A MOSFET driver, SOIC package,-40°C to +125°C.
		d) TC4432VOA-VAO: 1.5A MOSFET driver, PDIP package, Automotive Qualified
Package:	JA = Ceramic Dual In-line (300 mil Body), 8-lead * OA = Plastic SOIC, (150 mil Body), 8-lead OA713 = Plastic SOIC, (150 mil Body), 8-lead (Tape and Reel)	
	PA = Plastic DIP (300 mil Body), 8-lead* *	
	* Offered in E-temp range only * * The only package offered in the V temp range	
Qualification:	Blank = Standard Part	
	VAO = Automotive AEC-Q100 Qualified	
	*All currently available VAO variants are shown in the examples.  Contact your Local Microchip sales office to request	
	automotive qualified variants for other package types	

TC443	31	/T	$C\Delta$	43	2
$I \cup TT$	JI.	/ I '	VT	T	

NOTES:

#### Note the following details of the code protection feature on Microchip products:

- Microchip products meet the specifications contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is secure when used in the intended manner, within operating specifications, and under normal conditions.
- Microchip values and aggressively protects its intellectual property rights. Attempts to breach the code protection features of Microchip product is strictly prohibited and may violate the Digital Millennium Copyright Act.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of its code. Code protection does not
  mean that we are guaranteeing the product is "unbreakable" Code protection is constantly evolving. Microchip is committed to
  continuously improving the code protection features of our products.

This publication and the information herein may be used only with Microchip products, including to design, test, and integrate Microchip products with your application. Use of this information in any other manner violates these terms. Information regarding device applications is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. Contact your local Microchip sales office for additional support or, obtain additional support at <a href="https://www.microchip.com/en-us/support/design-help/client-support-services">https://www.microchip.com/en-us/support/design-help/client-support-services</a>.

THIS INFORMATION IS PROVIDED BY MICROCHIP "AS IS". MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION INCLUDING BUT NOT LIMITED TO ANY IMPLIED WARRANTIES OF NON-INFRINGEMENT, MERCHANTABILITY, AND FITNESS FOR A PARTICULAR PURPOSE, OR WARRANTIES RELATED TO ITS CONDITION, QUALITY, OR PERFORMANCE.

IN NO EVENT WILL MICROCHIP BE LIABLE FOR ANY INDIRECT, SPECIAL, PUNITIVE, INCIDENTAL, OR CONSEQUENTIAL LOSS, DAMAGE, COST, OR EXPENSE OF ANY KIND WHATSOEVER RELATED TO THE INFORMATION OR ITS USE, HOWEVER CAUSED, EVEN IF MICROCHIP HAS BEEN ADVISED OF THE POSSIBILITY OR THE DAMAGES ARE FORESEEABLE. TO THE FULLEST EXTENT ALLOWED BY LAW, MICROCHIP'S TOTAL LIABILITY ON ALL CLAIMS IN ANY WAY RELATED TO THE INFORMATION OR ITS USE WILL NOT EXCEED THE AMOUNT OF FEES, IF ANY, THAT YOU HAVE PAID DIRECTLY TO MICROCHIP FOR THE INFORMATION.

Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

For information regarding Microchip's Quality Management Systems, please visit <a href="https://www.microchip.com/quality.">www.microchip.com/quality.</a>

#### **Trademarks**

The Microchip name and logo, the Microchip logo, Adaptec, AVR, AVR logo, AVR Freaks, BesTime, BitCloud, CryptoMemory, CryptoRF, dsPIC, flexPWR, HELDO, IGLOO, JukeBlox, KeeLoq, Kleer, LANCheck, LinkMD, maXStylus, maXTouch, MediaLB, megaAVR, Microsemi, Microsemi logo, MOST, MOST logo, MPLAB, OptoLyzer, PIC, picoPower, PICSTART, PIC32 logo, PolarFire, Prochip Designer, QTouch, SAM-BA, SenGenuity, SpyNIC, SST, SST Logo, SuperFlash, Symmetricom, SyncServer, Tachyon, TimeSource, tinyAVR, UNI/O, Vectron, and XMEGA are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

AgileSwitch, APT, ClockWorks, The Embedded Control Solutions Company, EtherSynch, Flashtec, Hyper Speed Control, HyperLight Load, Libero, motorBench, mTouch, Powermite 3, Precision Edge, ProASIC, ProASIC Plus, ProASIC Plus logo, Quiet- Wire, SmartFusion, SyncWorld, Temux, TimeCesium, TimeHub, TimePictra, TimeProvider, TrueTime, and ZL are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Adjacent Key Suppression, AKS, Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, Augmented Switching, BlueSky, BodyCom, Clockstudio, CodeGuard, CryptoAuthentication, CryptoAutomotive, CryptoCompanion, CryptoController, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, Espresso T1S, EtherGREEN, GridTime, IdealBridge, In-Circuit Serial Programming, ICSP, INICnet, Intelligent Paralleling, IntelliMOS, Inter-Chip Connectivity, JitterBlocker, Knob-on-Display, KoD, maxCrypto, maxView, memBrain, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, PowerSmart, PureSilicon, QMatrix, REAL ICE, Ripple Blocker, RTAX, RTG4, SAM-ICE, Serial Quad I/O, simpleMAP, SimpliPHY, SmartBuffer, SmartHLS, SMART-I.S., storClad, SQI, SuperSwitcher, SuperSwitcher II, Switchtec, SynchroPHY, Total Endurance, Trusted Time, TSHARC, USBCheck, VariSense, VectorBlox, VeriPHY, ViewSpan, WiperLock, XpressConnect, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

The Adaptec logo, Frequency on Demand, Silicon Storage Technology, and Symmcom are registered trademarks of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2002-2022, Microchip Technology Incorporated and its subsidiaries.

All Rights Reserved.

ISBN: 978-1-6683-1749-5



# **Worldwide Sales and Service**

#### **AMERICAS**

Corporate Office 2355 West Chandler Blvd. Chandler, AZ 85224-6199

Tel: 480-792-7200 Fax: 480-792-7277 Technical Support:

http://www.microchip.com/ support

Web Address:

www.microchip.com

Atlanta Duluth, GA

Tel: 678-957-9614 Fax: 678-957-1455

**Austin, TX** Tel: 512-257-3370

**Boston** 

Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL

Tel: 630-285-0071 Fax: 630-285-0075

Dallas

Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

**Detroit** Novi. MI

Tel: 248-848-4000

Houston, TX

Tel: 281-894-5983 Indianapolis

Noblesville, IN Tel: 317-773-8323 Fax: 317-773-5453 Tel: 317-536-2380

Los Angeles

Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608 Tel: 951-273-7800

**Raleigh, NC** Tel: 919-844-7510

New York, NY Tel: 631-435-6000

**San Jose, CA** Tel: 408-735-9110 Tel: 408-436-4270

**Canada - Toronto** Tel: 905-695-1980 Fax: 905-695-2078

#### ASIA/PACIFIC

Australia - Sydney Tel: 61-2-9868-6733

**China - Beijing** Tel: 86-10-8569-7000

China - Chengdu Tel: 86-28-8665-5511

**China - Chongqing** Tel: 86-23-8980-9588

**China - Dongguan** Tel: 86-769-8702-9880

**China - Guangzhou** Tel: 86-20-8755-8029

China - Hangzhou Tel: 86-571-8792-8115

China - Hong Kong SAR Tel: 852-2943-5100

**China - Nanjing** Tel: 86-25-8473-2460

China - Qingdao Tel: 86-532-8502-7355

China - Shanghai

Tel: 86-21-3326-8000 China - Shenyang

Tel: 86-24-2334-2829

**China - Shenzhen** Tel: 86-755-8864-2200

**China - Suzhou** Tel: 86-186-6233-1526

**China - Wuhan** Tel: 86-27-5980-5300

**China - Xian** Tel: 86-29-8833-7252

China - Xiamen

Tel: 86-592-2388138 **China - Zhuhai** Tel: 86-756-3210040

#### ASIA/PACIFIC

India - Bangalore Tel: 91-80-3090-4444

India - New Delhi Tel: 91-11-4160-8631

India - Pune Tel: 91-20-4121-0141

Japan - Osaka

Tel: 81-6-6152-7160

**Japan - Tokyo** Tel: 81-3-6880- 3770

Korea - Daegu Tel: 82-53-744-4301

Korea - Seoul Tel: 82-2-554-7200

Malaysia - Kuala Lumpur Tel: 60-3-7651-7906

Malaysia - Penang Tel: 60-4-227-8870

Philippines - Manila Tel: 63-2-634-9065

**Singapore** Tel: 65-6334-8870

**Taiwan - Hsin Chu** Tel: 886-3-577-8366

Taiwan - Kaohsiung Tel: 886-7-213-7830

**Taiwan - Taipei** Tel: 886-2-2508-8600

Thailand - Bangkok Tel: 66-2-694-1351

Vietnam - Ho Chi Minh Tel: 84-28-5448-2100

#### **EUROPE**

**Austria - Wels** Tel: 43-7242-2244-39

Fax: 43-7242-2244-393

**Denmark - Copenhagen** Tel: 45-4485-5910 Fax: 45-4485-2829

Finland - Espoo Tel: 358-9-4520-820

France - Paris
Tel: 33-1-69-53-63-20
Fax: 33-1-69-30-90-79

Germany - Garching

Tel: 49-8931-9700

Germany - Haan

Tel: 49-2129-3766400 Germany - Heilbronn

Tel: 49-7131-72400 **Germany - Karlsruhe** Tel: 49-721-625370

**Germany - Munich** Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Germany - Rosenheim Tel: 49-8031-354-560

Israel - Ra'anana Tel: 972-9-744-7705

Italy - Milan

Tel: 39-0331-742611 Fax: 39-0331-466781

**Italy - Padova** Tel: 39-049-7625286

**Netherlands - Drunen** Tel: 31-416-690399 Fax: 31-416-690340

Norway - Trondheim Tel: 47-7288-4388

**Poland - Warsaw** Tel: 48-22-3325737

Romania - Bucharest Tel: 40-21-407-87-50

**Spain - Madrid** Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

Sweden - Gothenberg Tel: 46-31-704-60-40

Sweden - Stockholm Tel: 46-8-5090-4654

**UK - Wokingham** Tel: 44-118-921-5800 Fax: 44-118-921-5820